

**DB, DW, OR PW PACKAGE** 

(TOP VIEW)

FEATURES

- Bidirectional Voltage Translator
- 5.5 V on A Port and 2.7 V to 3.6 V on B Port
- Control Inputs V<sub>IH</sub>/V<sub>IL</sub> Levels Are Referenced to V<sub>CCA</sub> Voltage
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

## **DESCRIPTION/ORDERING INFORMATION**

This 8-bit (octal) noninverting bus transceiver contains two separate supply rails; B port has  $V_{CCB}$ , which is set at 3.3 V, and A port has  $V_{CCA}$ , which is set at 5 V. This allows for translation from a 3.3-V to a 5-V environment, and vice versa.

(5 V) V <sub>CCA</sub> [	1 U	24	] V <sub>CCB</sub> (3.3 V)
DIR	2	23	] V <sub>CCB</sub> (3.3 V)
A1 [	3	22	] <u>oe</u>
A2 [	4	21	] B1
A3 [	5	20	] B2
A4 [	6	19	] B3
A5 [	7	18	] B4
A6 [	8	17	] B5
A7 [	9	16	] B6
A8 [	10	15	] B7
GND [	11	14	] B8

GND 12

13 🛛 GND

The SN74LVC4245A is designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable ( $\overline{OE}$ ) input can be used to disable the device so the buses are effectively isolated. The control circuitry (DIR,  $\overline{OE}$ ) is powered by V<sub>CCA</sub>.

The SN74LVC4245A pinout allows the designer to switch to a normal all-3.3-V or all-5-V 20-pin '245 device without board re-layout. The designer uses the data paths for pins 2–11 and 14–23 of the SN74LVC4245A to align with the conventional '245 pinout.

T <sub>A</sub>	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING	
	SOIC - DW	Tube of 25	SN74LVC4245ADW	LVC4245A	
	30IC - DW	Reel of 2000	SN74LVC4245ADWR	LV04245A	
–40°C to 85°C	SSOP – DB	Reel of 2000	SN74LVC4245ADBR	LJ245A	
-40 C 10 85 C		Tube of 60	SN74LVC4245APW		
	TSSOP – PW	Reel of 2000	SN74LVC4245APWR	LJ245A	
		Reel of 250	SN74LVC4245APWT		

#### **ORDERING INFORMATION**

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

	INPUT	ſS	OPERATION
C	)E	DIR	OPERATION
	L	L	B data to A bus
	L	Н	A data to B bus
I	H	Х	Isolation

**FUNCTION TABLE** 

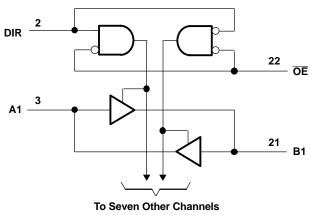


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SCAS375H-MARCH 1994-REVISED MARCH 2005



### LOGIC DIAGRAM (POSITIVE LOGIC)



# Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range for  $V_{CCA}$  = 4.5 V to 5.5 V (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CCA</sub>	Supply voltage range		-0.5	6.5	V
V	Innut voltogo rongo	A port <sup>(2)</sup>	-0.5	V <sub>CCA</sub> + 0.5	V
VI	Input voltage range	Control inputs	-0.5	6	v
Vo	Output voltage range	A port <sup>(2)</sup>	-0.5	V <sub>CCA</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
I <sub>O</sub>	Continuous output current			±50	mA
	Continuous current through each $V_{CCA}$ or G	SND		±100	mA
		DB package		63	
$\theta_{JA}$	Package thermal impedance <sup>(3)</sup>	DW package		46	°C/W
		PW package		88	
T <sub>stg</sub>	Storage temperature range		-65	150	°C

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) This value is limited to 6 V maximum.

(3) The package thermal impedance is calculated in accordance with JESD 51-7.

SCAS375H-MARCH 1994-REVISED MARCH 2005

## Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range for  $V_{CCB}$  = 2.7 V to 3.6 V (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CCB</sub>	Supply voltage range		-0.5	4.6	V
VI	Input voltage range	B port <sup>(2)</sup>	-0.5	V <sub>CCB</sub> + 0.5	V
Vo	Output voltage range	B port <sup>(2)</sup>	-0.5	V <sub>CCB</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
I <sub>O</sub>	Continuous output current			±50	mA
	Continuous current through $V_{CCB}$ or GND			±100	mA
		DB package		63	
$\theta_{JA}$	Package thermal impedance <sup>(3)</sup>	DW package		46	°C/W
		PW package		88	
T <sub>stg</sub>	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) This value is limited to 4.6 V maximum.

(3) The package thermal impedance is calculated in accordance with JESD 51-7.

## **Recommended Operating Conditions**<sup>(1)</sup>

for  $V_{CCA} = 4.5$  V to 5.5 V

		MIN	MAX	UNIT
V <sub>CCA</sub>	Supply voltage	4.5	5.5	V
V <sub>IH</sub>	High-level input voltage	2		V
VIL	Low-level input voltage		0.8	V
VIA	Input voltage	0	V <sub>CCA</sub>	V
V <sub>OA</sub>	Output voltage	0	V <sub>CCA</sub>	V
I <sub>OH</sub>	High-level output current		-24	mA
I <sub>OL</sub>	Low-level output current		24	mA
T <sub>A</sub>	Operating free-air temperature	-40	85	°C

(1) All unused inputs of the device must be held at the associated V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

## **Recommended Operating Conditions**<sup>(1)</sup>

for  $V_{CCB} = 2.7$  V to 3.6 V

			MIN	MAX	UNIT
V <sub>CCB</sub>	Supply voltage		2.7	3.6	V
VIH	High-level input voltage	$V_{CCB} = 2.7 \text{ V to } 3.6 \text{ V}$	2		V
V <sub>IL</sub>	Low-level input voltage	$V_{CCB} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8	V
V <sub>IB</sub>	Input voltage		0	V <sub>CCB</sub>	V
V <sub>OB</sub>	Output voltage		0	V <sub>CCB</sub>	V
	High-level output current	$V_{CCB} = 2.7 V$		-12	mA
ЮН	High-level output current	$V_{CCB} = 3 V$		-24	ША
		$V_{CCB} = 2.7 V$		12	mA
IOL	Low-level output current	V <sub>CCB</sub> = 3 V		24	ШA
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

All unused inputs of the device must be held at the associated V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

SCAS375H-MARCH 1994-REVISED MARCH 2005

## Electrical Characteristics<sup>(1)</sup>

over recommended operating free-air temperature range for  $V_{CCA}$  = 4.5 V to 5.5 V (unless otherwise noted)

P/	ARAMETER	TEST CONDITION	S V <sub>CCA</sub>	MIN T	YP <sup>(2)</sup> MAX	UNIT	
		100	4.5 V	4.3	4.3		
V <sub>OH</sub>		I <sub>OH</sub> = -100 μA	5.5 V	5.3		V	
V <sub>OL</sub> I <sub>I</sub> Control inputs I <sub>OZ</sub> <sup>(3)</sup> A port I <sub>CCA</sub> ΔI <sub>CCA</sub> <sup>(4)</sup>		4.5 V	3.7		V		
		$I_{OH} = -24 \text{ mA}$	5.5 V	4.7			
		1 100 1	4.5 V		0.2		
	$V_{OH}$ $V_{OL}$ $I_{I}$ $I_{OZ}^{(3)}$ $I_{CCA}$ $C_{i}$ $C_{OH}$ $C_{OH}$ $C_{OH}$ $C_{OH}$ $C_{OH}$	I <sub>OL</sub> = 100 μA		5.5 V		0.2	V
VOL			4.5 V		0.55	V	
		$I_{OL} = 24 \text{ mA}$	5.5 V		0.55		
I <sub>I</sub>	Control inputs	$V_{I} = V_{CCA}$ or GND	5.5 V		±1	μA	
I <sub>OZ</sub> <sup>(3)</sup>	A port	$V_{O} = V_{CCA}$ or GND	5.5 V		±5	μA	
I <sub>CCA</sub>		$V_{I} = V_{CCA} \text{ or } GND, \qquad I_{O} = 0$	5.5 V		80	μA	
$\Delta I_{CCA}^{(4)}$		One input at 3.4 V, Other input	is at V <sub>CCA</sub> or GND 5.5 V		1.5	mA	
Ci	Control inputs	$V_{I} = V_{CCA}$ or GND	Open		5	pF	
Cio	A port	$V_{O} = V_{CCA}$ or GND	5 V		11	pF	

 V<sub>CCB</sub> = 2.7 V to 3.6 V
 All typical values are measured at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C.
 For I/O ports, the parameter I<sub>OZ</sub> includes the input leakage current.
 This is the increase in supply current for each input that is at one of the specified TTL voltage levels, rather than 0 V or the associated V<sub>CC</sub>.

## Electrical Characteristics<sup>(1)</sup>

over recommended operating free-air temperature range for V<sub>CCB</sub> = 2.7 V to 3.6 V (unless otherwise noted)

PARAMETER		TEST C	ONDITIONS	V <sub>CCB</sub>	MIN	TYP <sup>(2)</sup>	MAX	UNIT
		I <sub>OH</sub> = −100 μA		2.7 V to 3.6 V	$V_{CC} - 0.2$			
		1 10 10		2.7 V	2.2			
V <sub>OH</sub>		I <sub>OH</sub> = -12 mA		3 V	2.4			V
		I <sub>OH</sub> = -24 mA		3 V	2			
		I <sub>OL</sub> = 100 μA		2.7 V to 3.6 V			0.2	
V <sub>OL</sub>		I <sub>OL</sub> = 12 mA		2.7 V			0.4	V
		I <sub>OL</sub> = 24 mA		3 V			0.55	
I <sub>OZ</sub> <sup>(3)</sup>	B port	$V_{O} = V_{CCB}$ or GND		3.6 V			±5	μA
I <sub>CCB</sub>		$V_I = V_{CCB}$ or GND,	I <sub>O</sub> = 0	3.6 V			50	μA
$\Delta I_{CCB}^{(4)}$	)	One input at V <sub>CCB</sub> – 0.6 V,	Other inputs at $V_{CCB}$ or GND	2.7 V to 3.6 V			0.5	mA
C <sub>io</sub>	B port	$V_{O} = V_{CCB}$ or GND		3.3 V		11		pF

 V<sub>CCA</sub> = 5 V ± 0.5 V
 All typical values are measured at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C.
 For I/O ports, the parameter I<sub>OZ</sub> includes the input leakage current.
 This is the increase in supply current for each input that is at one of the specified TTL voltage levels, rather than 0 V or the associated TTL voltage levels. V<sub>CC</sub>.

SCAS375H-MARCH 1994-REVISED MARCH 2005

## **Switching Characteristics**

over recommended operating free-air temperature range,  $C_L = 50 \text{ pF}$  (unless otherwise noted) (see Figure 1 and Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CCA}$ = 5 V ± $V_{CCB}$ = 2.7 V t	0.5 V, o 3.6 V	UNIT
	(INFOT)	(001-01)	MIN	MAX	
t <sub>PHL</sub>		В	1	6.3	20
t <sub>PLH</sub>	A	В	1	6.7	ns
t <sub>PHL</sub>	В	А	1	6.1	20
t <sub>PLH</sub>	В	A	1	5	ns
t <sub>PZL</sub>	- <u>OE</u>	А	1	9	20
t <sub>PZH</sub>	UE UE	A	1	8.1	ns
t <sub>PZL</sub>	OE	В	1	8.8	20
t <sub>PZH</sub>	UE UE	D	1	9.8	ns
t <sub>PLZ</sub>	OE	А	1	7	20
t <sub>PHZ</sub>	J	A	1	5.8	ns
t <sub>PLZ</sub>	OE	В	1	7.7	20
t <sub>PHZ</sub>	JE	В	1	7.8	ns

### **Operating Characteristics**

 $V_{CCA}$  = 4.5 V to 5.5 V,  $V_{CCB}$  = 2.7 V to 3.6 V,  $T_A$  = 25°C

	PARAMETER	TEST C	ONDITIONS	TYP	UNIT	
	Dower dissipation consultance per transaciver	Outputs enabled	<b>C</b> 0	£ 10 MU	39.5	~ <b>F</b>
C <sub>pd</sub>	Power dissipation capacitance per transceiver	Outputs disabled	$C_{L} = 0,$	f = 10 MHz	5	pF

### Power-Up Considerations<sup>(1)</sup>

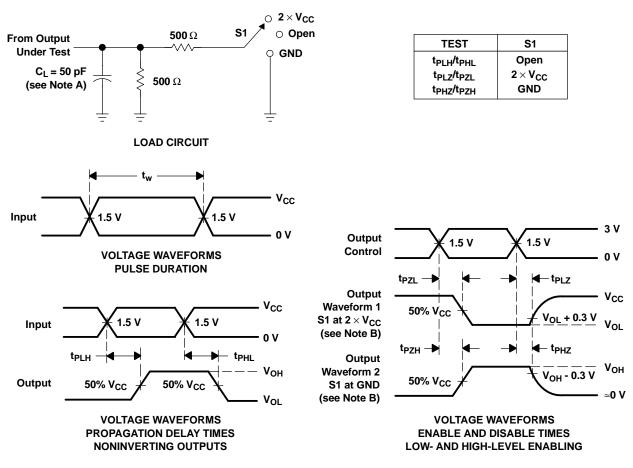
TI level-translation devices offer an opportunity for successful mixed-voltage signal design. A proper power-up sequence always should be followed to avoid excessive supply current, bus contention, oscillations, or other anomalies caused by improperly biased device pins. Take these precautions to guard against such power-up problems:

- 1. Connect ground before any supply voltage is applied.
- 2. Power up the control side of the device (V<sub>CCA</sub> for all four of these devices).
- 3. Tie  $\overline{OE}$  to V<sub>CCA</sub> with a pullup resistor so that it ramps with V<sub>CCA</sub>.
- Depending on the direction of the data path, DIR can be high or low. If DIR high is needed (A data to B bus), ramp it with V<sub>CCA</sub>. Otherwise, keep DIR low.
- (1) Refer to the TI application report, Texas Instruments Voltage-Level-Translation Devices, literature number SCEA021.

SCAS375H-MARCH 1994-REVISED MARCH 2005



### PARAMETER MEASUREMENT INFORMATION A PORT



- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>Q</sub> = 50  $\Omega$ , t<sub>r</sub>  $\leq$  2.5 ns. t<sub>f</sub>  $\leq$  2.5 ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E. All parameters and waveforms are not applicable to all devices.

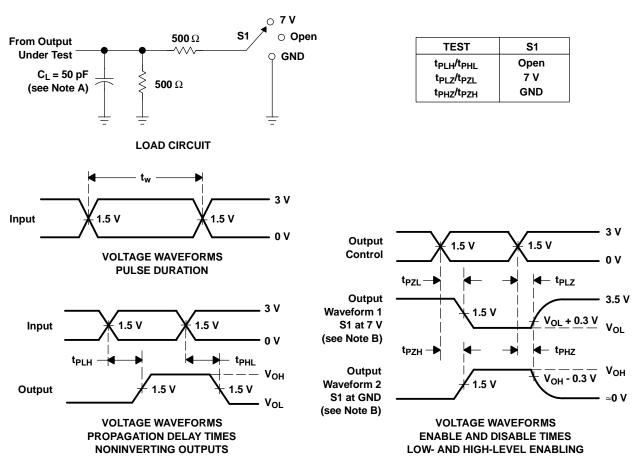
#### Figure 1. Load Circuit and Voltage Waveforms

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## SN74LVC4245A OCTAL BUS TRANSCEIVER AND 3.3-V TO 5-V SHIFTER WITH 3-STATE OUTPUTS

SCAS375H-MARCH 1994-REVISED MARCH 2005

#### PARAMETER MEASUREMENT INFORMATION B PORT



- NOTES: A.  $C_L$  includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>r</sub>  $\leq$  2.5 ns, t<sub>f</sub>  $\leq$  2.5 ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E. All parameters and waveforms are not applicable to all devices.

#### Figure 2. Load Circuit and Voltage Waveforms



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### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
SN74LVC4245ADBR	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC4245ADBRE4	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC4245ADBRG4	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC4245ADW	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC4245ADWE4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC4245ADWG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC4245ADWR	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC4245ADWRE4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC4245ADWRG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC4245APW	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC4245APWE4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC4245APWG4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC4245APWR	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC4245APWRE4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC4245APWRG4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC4245APWT	ACTIVE	TSSOP	PW	24	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC4245APWTE4	ACTIVE	TSSOP	PW	24	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	



14-Feb-2012

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
SN74LVC4245APWTG4	ACTIVE	TSSOP	PW	24	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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#### OTHER QUALIFIED VERSIONS OF SN74LVC4245A :

Enhanced Product: SN74LVC4245A-EP

NOTE: Qualified Version Definitions:

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

# PACKAGE MATERIALS INFORMATION

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## TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



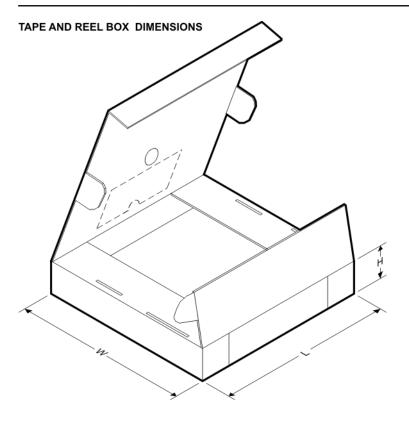
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC4245ADBR	SSOP	DB	24	2000	330.0	16.4	8.2	8.8	2.5	12.0	16.0	Q1
SN74LVC4245ADWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
SN74LVC4245ADWRG4	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
SN74LVC4245APWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1
SN74LVC4245APWT	TSSOP	PW	24	250	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1

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# PACKAGE MATERIALS INFORMATION

11-Oct-2012



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC4245ADBR	SSOP	DB	24	2000	367.0	367.0	38.0
SN74LVC4245ADWR	SOIC	DW	24	2000	367.0	367.0	45.0
SN74LVC4245ADWRG4	SOIC	DW	24	2000	367.0	367.0	45.0
SN74LVC4245APWR	TSSOP	PW	24	2000	367.0	367.0	38.0
SN74LVC4245APWT	TSSOP	PW	24	250	367.0	367.0	38.0

DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AD.



PW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 B. This drawing is subject to change without notice.

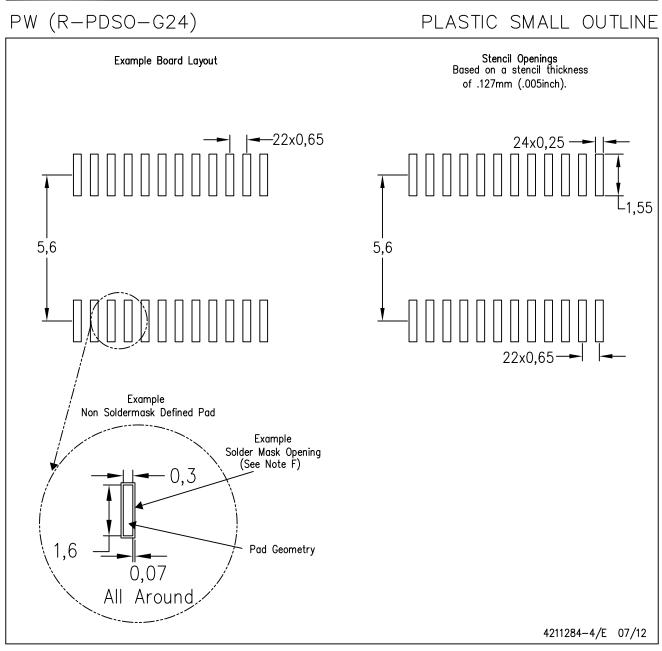
Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



## LAND PATTERN DATA



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.

E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



## **MECHANICAL DATA**

MSSO002E - JANUARY 1995 - REVISED DECEMBER 2001

## DB (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150



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